DESCRIPTION

The SPN1423A is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

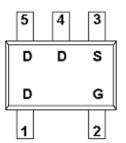
APPLICATIONS

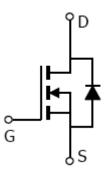
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

- 20V/4.0A,RDS(ON)= $80m\Omega(@)V$ GS=4.5V
- \bullet 20V/3.4A,RDS(ON)=90m $\Omega(a)$ VGS=2.5V
- 20V/2.8A,RDS(ON)= $110m\Omega$ @VGS=1.8V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- \bullet SOT-353 (SC 70) package design

PIN CONFIGURATION (SOT-353; SC-70)





PART MARKING



Y: Year Code W: Week Code

PIN DESCRIPTION						
Pin	Symbol	Description				
2	G	Gate				
3	S	Source				
1,4,5	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1423AS35RGB	SOT-353	2A

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN1423AS35RGB : Tape Reel ; Pb − Free ; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

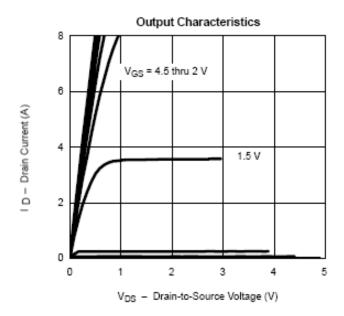
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Dusin Cumant/Ty-1509C)	Ta=25°C	- ID	2.4	A	
Continuous Drain Current(TJ=150°C)	Ta=70°C		1.7	A	
Pulsed Drain Current		Ірм	6	A	
Continuous Source Current(Diode Conduction)		Is	1.6	A	
Dames Dissipation	Ta=25°C	PD	0.95	W	
Power Dissipation	Ta=70°C		051	W	
Operating Junction Temperature		Tı	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	105	°C/W	

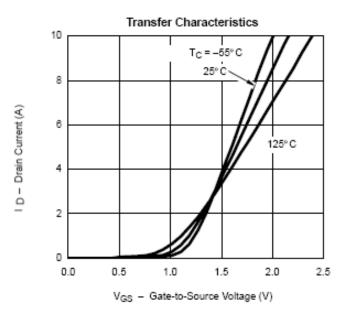
ELECTRICAL CHARACTERISTICS

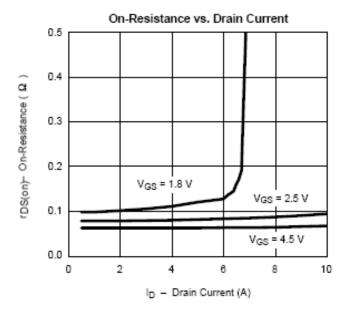
(TA=25°C Unless otherwise noted)

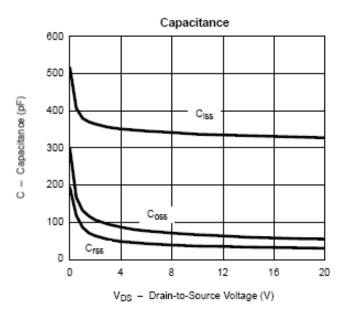
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static	I		1	ı	ı	_1
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	20			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.4		1.0	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA
Zero Gate Voltage Drain Current		V _{DS} =20V,V _{GS} =0V			1	uA
	Idss	Vds=20V,Vgs=0V Tj=55°C			5	
On-State Drain Current	ID(on)	$V_{DS} \leq 5V, V_{GS} = 4.5V$	6			A
		Vgs=4.5V,Id=4.0A		0.065	0.080	Ω
Drain-Source On-Resistance	RDS(on)	Vgs=2.5V,Id=3.4A		0.075	0.090	
		VGS=1.8V,ID=2.8A		0.090	0.110	
Forward Transconductance	gfs	VDS=5V,ID=-3.6A		10		S
Diode Forward Voltage	Vsd	Is=1.6A,VGS=0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg			4.8	8	nC
Gate-Source Charge	Qgs	V _{DS} =6V,V _{GS} =4.5V I _D =2.8A		1.0		
Gate-Drain Charge	Qgd	10-2.071		1.0		
Input Capacitance	Ciss			485		pF
Output Capacitance	Coss	VDS=6V,VGS=0V f=1MHz		85		
Reverse Transfer Capacitance	Crss			40		
Turn-On Time	td(on)			8	14	nS
	t r	$V_{DD}=6V,R_{L}=6\Omega$		12	18	
Turn-Off Time	td(off)	ID=1.0A,VGEN=4.5V RG= 6Ω		30	35	
	tf			12	16	

TYPICAL CHARACTERISTICS

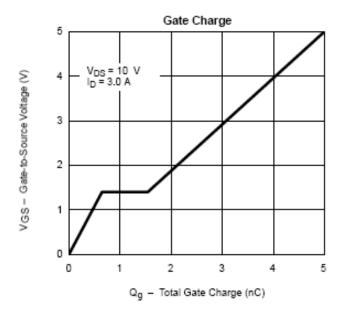


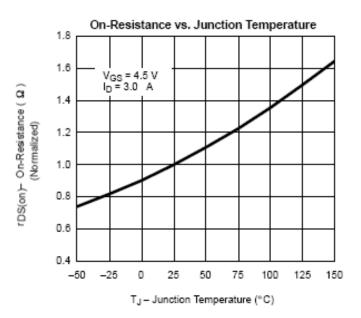


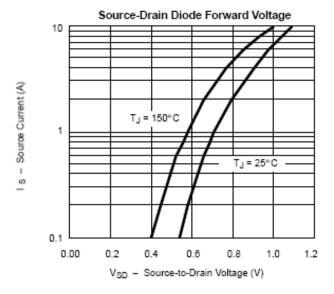


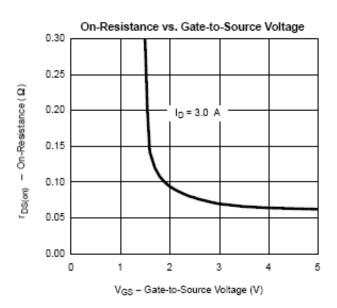


TYPICAL CHARACTERISTICS



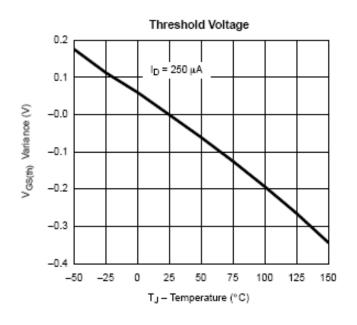


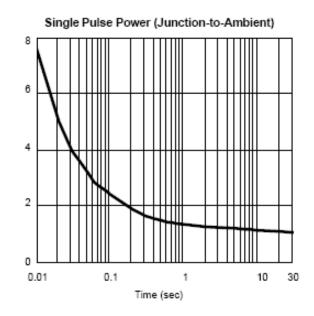


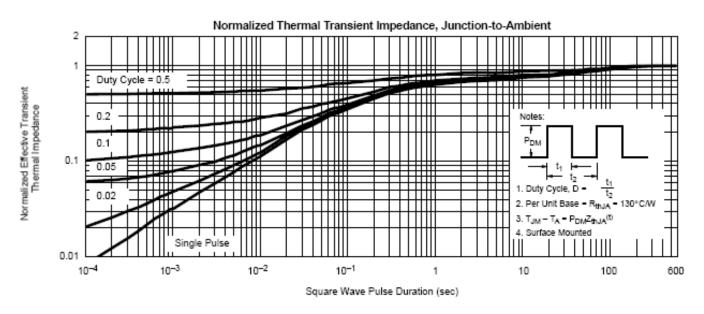


Power (W)

TYPICAL CHARACTERISTICS







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